



45°VIEW

NOTES

1. MATERIAL: UVFS
2. COATING(S1): BROADBAND DIELECTRIC COATING
Ravg > 99% @ 400 nm–750 nm, 0° –45° AOI
3. CLEAR APERTURE(S1): > 90% CA
4. SURFACE QUALITY(S1): 10/5(S/D)
5. SURFACE FLATNESS(S1): $\lambda / 10 @ 633 \text{ nm}$
6. PARALLELISM(S1, S2): < 3 arcmin
7. CHAMFER: < 0.2 mm, 45°
8. BACK SURFACE (S2): FINE GROUND

DRAWING PROJECTION			LBTEK			
	NAME	DATE				
DRAWN	Lynne	FEB./25th/24	BROADBAND DIELECTRIC-COATED PLANO MIRROR ELLIPSE: 18.0 mm x 12.7 mm, 400 nm–750 nm			
APPROVAL	CWZ	FEB./25th/24	MATERIAL	WEIGHT	SCALE	REV
FOR INFORMATION ONLY NOT FOR MANUFACTURING PURPOSES			UVFS	2.37 g	3:1	A